

MMVL2101T1

Preferred Device

Silicon Tuning Diode

These devices are designed in the popular Plastic Surface Mount Package for high volume requirements of FM Radio and TV tuning and AFC, general frequency control and tuning applications. They provide solid-state reliability in replacement of mechanical tuning methods.

Features

- High Q
- Controlled and Uniform Tuning Ratio
- Standard Capacitance Tolerance – 10%
- Complete Typical Design Curves
- Pb-Free Package is Available

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Continuous Reverse Voltage	V_R	30	Vdc
Peak Forward Current	I_F	200	mAdc

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation FR-5 Board, $T_A = 25^\circ\text{C}$ (Note 1) Derate above 25°C	P_D	200 1.57	mW mW/ $^\circ\text{C}$
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	635	$^\circ\text{C}/\text{W}$
Junction and Storage Temperature	T_J, T_{stg}	150	$^\circ\text{C}$

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

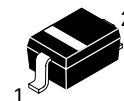
1. FR-4 Minimum Pad



ON Semiconductor®

<http://onsemi.com>

30 VOLTS VOLTAGE VARIABLE CAPACITANCE DIODE



PLASTIC
SOD-323
CASE 477
STYLE 1

MARKING DIAGRAM



4G = Device Code
M = Date Code*
▪ = Pb-Free Package

(Note: Microdot may be in either location)
*Date Code orientation may vary depending upon manufacturing location.

ORDERING INFORMATION

Device	Package	Shipping†
MMVL2101T1	SOD-323	3000 / Tape & Reel
MMVL2101T1G	SOD-323 (Pb-Free)	3000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

Preferred devices are recommended choices for future use and best overall value.

MMVL2101T1

ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise noted)

Characteristic	Symbol	Min	Typ	Max	Unit
Reverse Breakdown Voltage ($I_R = 10\ \mu\text{A}$)	$V_{(BR)R}$	30	–	–	Vdc
Reverse Voltage Leakage Current ($V_R = 25\ \text{Vdc}$, $T_A = 25^\circ\text{C}$)	I_R	–	–	0.1	μA
Diode Capacitance Temperature Coefficient ($V_R = 4.0\ \text{Vdc}$, $f = 1.0\ \text{MHz}$)	TC_C	–	280	–	ppm/ $^\circ\text{C}$

Device	C_T , Diode Capacitance $V_R = 4.0\ \text{Vdc}$, $f = 1.0\ \text{MHz}$ pF			Q , Figure of Merit $V_R = 4.0\ \text{Vdc}$, $f = 50\ \text{MHz}$	TR, Tuning Ratio C_2/C_{30} $f = 1.0\ \text{MHz}$		
	Min	Nom	Max	Typ	Min	Typ	Max
MMVL2101T1	6.1	6.8	7.5	450	2.5	2.7	3.2

PARAMETER TEST METHODS

1. C_T , DIODE CAPACITANCE

($C_T = C_C + C_J$). C_T is measured at 1.0 MHz using a capacitance bridge (Boonton Electronics Model 75A or equivalent).

2. TR, TUNING RATIO

TR is the ratio of C_T measured at 2.0 Vdc divided by C_T measured at 30 Vdc.

3. Q, FIGURE OF MERIT

Q is calculated by taking the G and C readings of an admittance bridge at the specified frequency and substituting in the following equations:

$$Q = \frac{2\pi f C}{G}$$

(Boonton Electronics Model 33AS8 or equivalent). Use Lead Length $\approx 1/16''$.

4. TC_C , DIODE CAPACITANCE TEMPERATURE COEFFICIENT

TC_C is guaranteed by comparing C_T at $V_R = 4.0\ \text{Vdc}$, $f = 1.0\ \text{MHz}$, $T_A = -65^\circ\text{C}$ with C_T at $V_R = 4.0\ \text{Vdc}$, $f = 1.0\ \text{MHz}$, $T_A = +85^\circ\text{C}$ in the following equation, which defines TC_C :

$$TC_C = \left| \frac{C_T(+85^\circ\text{C}) - C_T(-65^\circ\text{C})}{85 + 65} \right| \cdot \frac{10^6}{C_T(25^\circ\text{C})}$$

Accuracy limited by measurement of C_T to $\pm 0.1\ \text{pF}$.

TYPICAL DEVICE CHARACTERISTICS

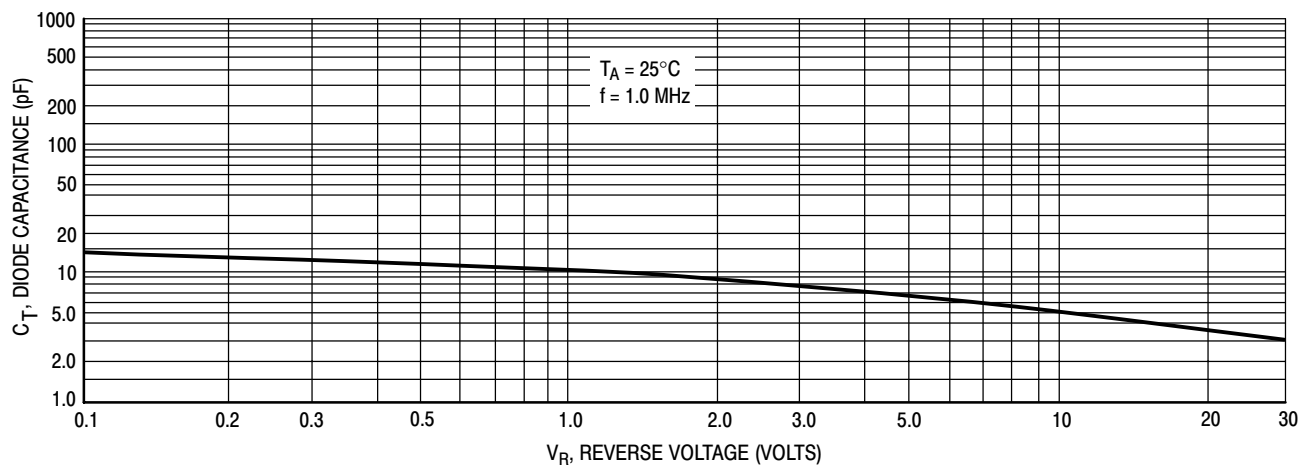


Figure 1. Diode Capacitance versus Reverse Voltage

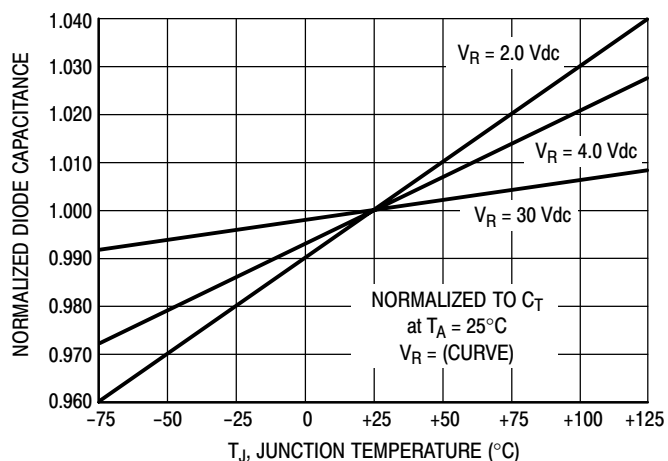


Figure 2. Normalized Diode Capacitance versus Junction Temperature

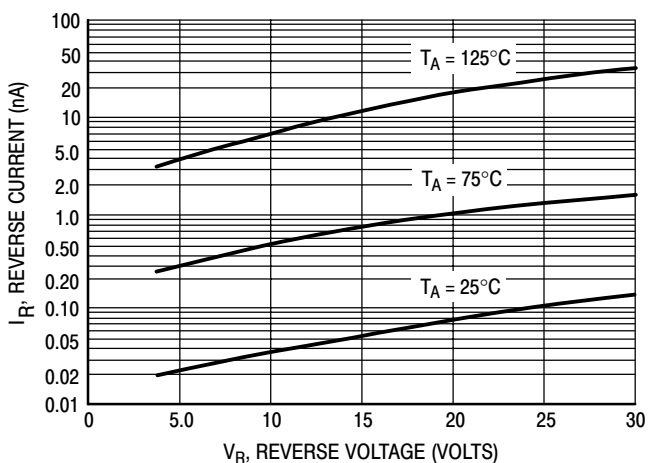


Figure 3. Reverse Current versus Reverse Bias Voltage

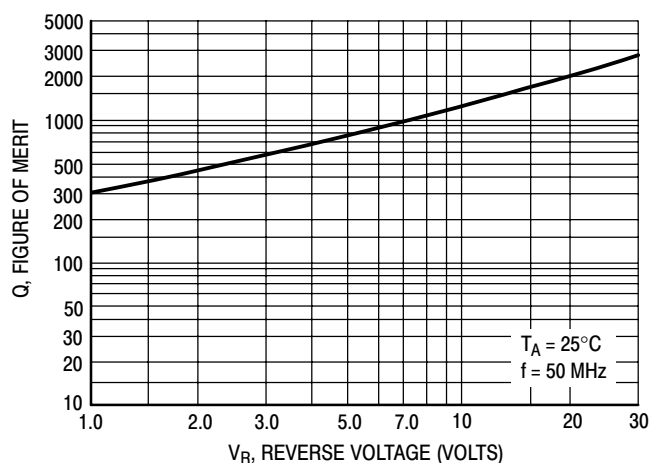


Figure 4. Figure of Merit versus Reverse Voltage

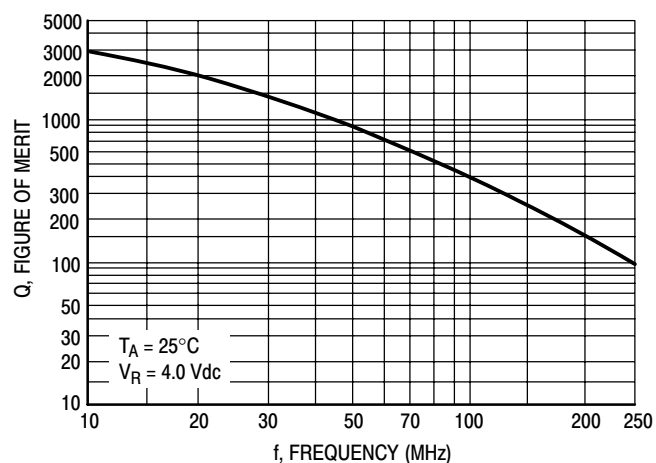
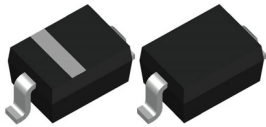
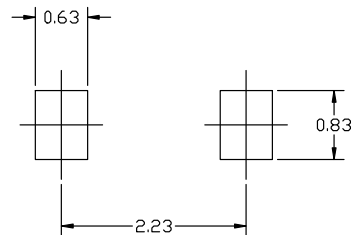
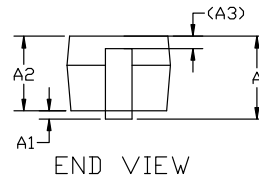
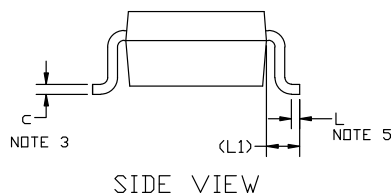
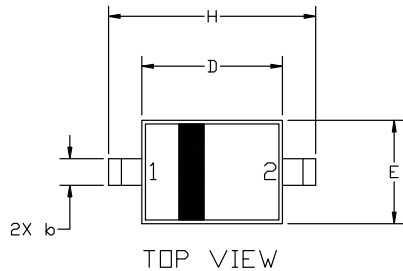


Figure 5. Figure of Merit versus Frequency


SOD-323 1.70x1.25x0.85
CASE 477
ISSUE K

DATE 11 MAR 2024

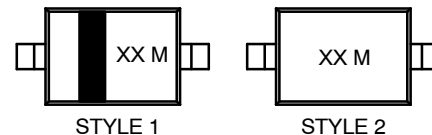


*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference manual, SOLDERRM/D.

NOTES:

1. DIMENSIONING AND TOLERANCING AS PER ASME Y14.5M, 2018.
2. CONTROLLING DIMENSION: MILLIMETERS.
3. LEAD THICKNESS SPECIFIED PER L/F DRAWING WITH SOLDER PLATING.
4. DIMENSIONS A AND B DO NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS.
5. DIMENSION L IS MEASURE FROM END OF RADIUS.

DIM	MILLIMETERS		
	MIN.	NOM.	MAX.
A	0.80	0.90	1.00
A1	0.00	0.05	0.10
A2	0.75	0.85	0.95
A3	0.15 (REF)		
b	0.25	0.32	0.4
c	0.09	0.12	0.18
D	1.60	1.70	1.80
E	1.15	1.25	1.35
H	2.30	2.50	2.70
L	0.08	---	---
L1	0.40 (REF)		

GENERIC MARKING DIAGRAM*


XX = Specific Device Code
M = Date Code

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

STYLE 1:
PIN 1: CATHODE (POLARITY BAND)
2: ANODE

STYLE 2:
NO POLARITY

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DESCRIPTION:	SOD-323 1.70x1.25x0.85	PAGE 1 OF 1

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